

^{217}Pa α decay (3.8 ms) 2002He29, 2000He17, 1968Va18

| Type | Author | History Citation | Literature Cutoff Date |
|-----------------|---------------|---------------------|------------------------|
| Full Evaluation | M. S. Basunia | NDS 181, 475 (2022) | 1-Jan-2022 |

Parent: ^{217}Pa : E=0.0; $J^\pi=9/2^-$; $T_{1/2}=3.8$ ms 2; $Q(\alpha)=8489$ 4; % α decay=100.0

$^{217}\text{Pa}-J^\pi$: Based on favored α -decay chain from ^{217}Pa g.s. to g.s. of ^{213}Ac , $J^\pi=9/2^-$, to g.s. of ^{209}Fr , $J^\pi=9/2^-$ (firm $J^\pi=9/2-(^{209}\text{Fr})$ in 2015Ch30).

$^{217}\text{Pa}-T_{1/2}$: From 2018Ko01 (A=217 evaluation).

$^{217}\text{Pa}-Q(\alpha)$: From 2021Wa16.

Others: 1998Ik01, 1996An21, 1979Sc09, and 2005YeZZ.

2002He29: ^{217}Pa produced through $^{181}\text{Ta}(^{40}\text{Ar},4\text{n})^{217}\text{Pa}$; Target: 99.988% natural tantalum; E=182 MeV; Detector: 16-strip PIPS-detector, Ge-Clover detector of 4 crystals; Measured: $E\alpha$, $I\alpha$, α - α coincidences.

2000He17: ^{217}Pa produced through $^{170}\text{Er}(^{51}\text{V},4\text{n})^{217}\text{Pa}$; E=214-286 MeV; Detector: 16-strip PIPS-detector, a HPGe detector; Measured: $E\alpha$, $I\alpha$.

1968Va18: ^{217}Pa produced through $^{206}\text{Pb}(^{20}\text{Ne},p8\text{n})^{217}\text{Pa}$ and $^{208}\text{Tl}(^{20}\text{Ne},11\text{n})^{217}\text{Pa}$; Detector: Semi; Measured: $E\alpha$.

1998Ik01: ^{217}Pa produced through $^{194}\text{Pt}(^{28}\text{Si},p4\text{n})^{217}\text{Pa}$; E=163-MeV and 175-MeV; Detector: double sided position sensitive strip detector; Measured: $E\alpha$, $T_{1/2}$.

1996An21: ^{217}Pa from $^{170}\text{Er}(^{51}\text{V},4\text{n})^{217}\text{Pa}$; E=28-87 MeV; Detector: ER are separated in flight, 16-strip PIPS detector, a HPGe detector; Measured: $E\alpha$, $T_{1/2}$.

1979Sc09: $^{181}\text{Ta}(^{40}\text{Ar},4\text{n})^{217}\text{Pa}$; E=165-202 MeV; Measured: $E\alpha$, $T_{1/2}$.

2005YeZZ: ^{217}Pa from $^{181}\text{Ta}(^{40}\text{Ar},4\text{n})^{217}\text{Pa}$; Detector: array of silicon strip, 7 HPGe, time-of-flight detectors; Measured $E\alpha$.

 ^{213}Ac Levels

| E(level) [†] | J^π | $T_{1/2}$ | Comments |
|-----------------------|---------|-----------|--|
| 0 | $9/2^-$ | 738 ms 16 | $J^\pi, T_{1/2}$: From Adopted Levels. E(level): Other: 468 6 from $E\alpha$ and $Q\alpha$. |
| 466.1 20 | | | E(level): Other: 616 6 from $E\alpha$ and $Q\alpha$. |
| 612.5 8 | | | E(level): Other: 634 6 from $E\alpha$ and $Q\alpha$. |
| 634.3 11 | | | J^π : In 2002He29, $J^\pi=(13/2^-)$ is presented for this level in the tentative partial decay scheme of ^{213}Ac . |

[†] From $E\gamma$. Values from the $E\alpha$ and $Q(\alpha)$ are listed in comments.

 α radiations

| $E\alpha$ | E(level) | $I\alpha^{\ddagger\#}$ | HF [†] | Comments |
|-----------|----------|------------------------|-----------------|--|
| 7710 5 | 634.3 | 0.3 2 | 7 5 | $E\alpha$: From 2002He29. |
| 7728 5 | 612.5 | 0.3 2 | 8 6 | $E\alpha$: From 2002He29. |
| 7873 5 | 466.1 | 0.4 2 | 18 9 | $E\alpha$: From 2002He29. |
| 8336 4 | 0 | 99 1 | 1.72 15 | $E\alpha$: Weighted average of 8337 5 (2002He29), 8334 15 (2000He17), 8330 50 (1998Ik01), 8330 10 (1996An21), 8334 15 (1979Sc09), and 8340 10 (1968Va18). |

[†] Using $r_0(^{213}\text{Ac})=1.491$ 21, unweighted average of $r_0(^{212}\text{Ra})=1.4695$ 14 and $r_0(^{214}\text{Th})=1.512$ 14 (2020Si16).

[‡] From 2002He29.

[#] Absolute intensity per 100 decays.

$^{217}\text{Pa } \alpha$ decay (3.8 ms) 2002He29,2000He17,1968Va18 (continued) $\gamma(^{213}\text{Ac})$

| E_γ^\dagger | $E_i(\text{level})$ | E_f | J_f^π |
|-----------------------|---------------------|-------|------------------|
| 466.1 [‡] 20 | 466.1 | 0 | 9/2 ⁻ |
| 612.5 [‡] 8 | 612.5 | 0 | 9/2 ⁻ |
| 634.3 [‡] 11 | 634.3 | 0 | 9/2 ⁻ |

[†] From 2002He29.[‡] Placement of transition in the level scheme is uncertain. $^{217}\text{Pa } \alpha$ decay (3.8 ms) 2002He29,2000He17,1968Va18

Legend

Decay Scheme